

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re Application of

Dominik EISERT et al.

Serial No.: 10/523,551

Filed: October 18, 2005

For: GaN-Based Radiation-Emitting Thin-Layered  
Semiconductor Component

Examiner: Nguyen, Joseph H.

Group Art: 2815

Commissioner for Patents  
Alexandria, VA 22313-1450

**AMENDMENT AFTER FINAL REJECTION**

SIR:

In response to the Final Office Action dated November 23, 2009, please amend the above-identified application as follows:

**Amendments to the Claims** are reflected in the listing of claims which begins on page 2 of this paper.

**Remarks/Arguments** begin on page 9 of this paper.